FAIRCHILD

SEMICONDUCTOR®

BD439/441

Medium Power Linear and Switching Applications

Complement to BD440, BD442 respectively

NPN Epitaxial Silicon Transistor



BD439/441

1. Emitter 2.Collector 3.Base

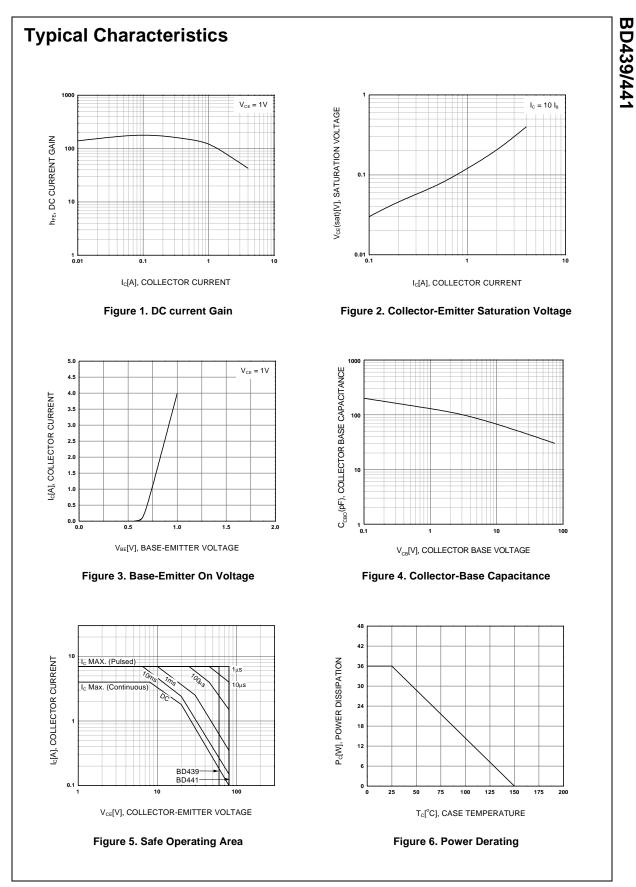
Absolute Maximum Ratings T_C=25°C unless otherwise noted

Symbol	Parameter	Value	Units
V _{CBO}	Collector-Base Voltage		
020	: BD439	60	V
	: BD441	80	V
V _{CES}	Collector-Emitter Voltage		
	: BD439	60	V
	: BD441	80	V
V _{CEO}	Collector-Emitter Voltage		
	: BD439	60	V
	: BD441	80	V
V _{EBO}	Emitter-Base Voltage	5	V
I _C	Collector Current (DC)	4	А
I _{CP}	*Collector Current (Pulse)	7	А
I _B	Base Current	1	А
I _B P _C	Collector Dissipation (T _C =25°C)	36	W
Т _Ј	Junction Temperature	150	°C
T _{STG}	Storage Temperature	- 65 ~ 150	°C

Electrical Characteristics $T_C=25^{\circ}C$ unless otherwise noted

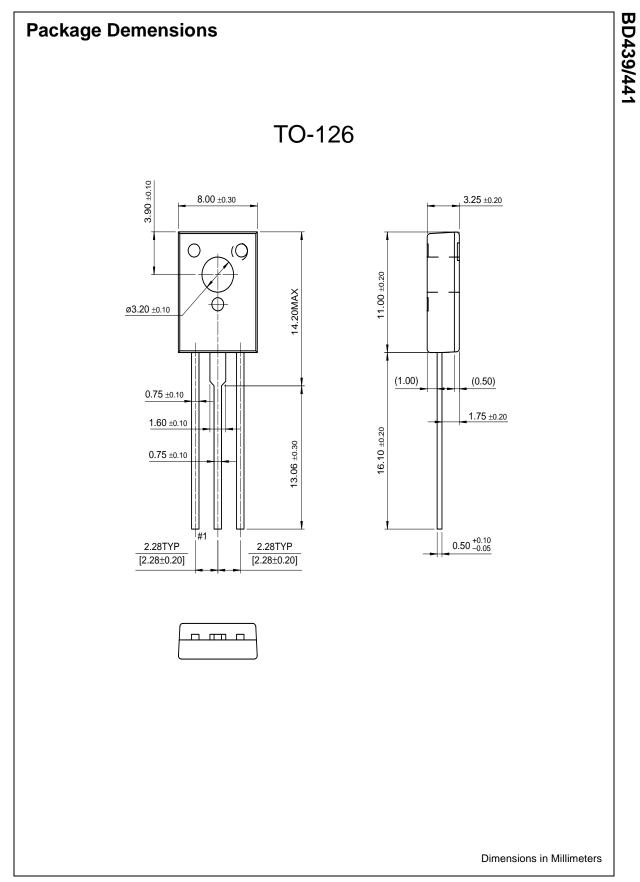
Symbol	Paramete	er	Test Condition	Min.	Тур.	Max.	Units
V _{CEO} (sus)	* Collector-Emitter Sustainin	ng Voltage					
		: BD439	I _C = 100mA, I _B = 0	60			V
		: BD441	-	80			V
I _{CBO}	Collector Cut-off Current	: BD439	$V_{CB} = 60V, I_E = 0$			100	μΑ
		: BD441	$V_{CB} = 80V, I_E = 0$			100	μΑ
I _{CES}	Collector Cut-off Current	: BD439	$V_{CE} = 60V, V_{BE} = 0$			100	μΑ
		: BD441	$V_{CE} = 80V, V_{BE} = 0$			100	μΑ
I _{EBO}	Emitter Cut-off Current		$V_{EB} = 5V, I_{C} = 0$			1	mA
h _{FE}	* DC Current Gain	: BD439	$V_{CE} = 5V, I_{C} = 10mA$	20	130		
		: BD441		15	130		
		: BD439	$V_{CE} = 1V, I_{C} = 500mA$	40	140		
		: BD441		40	140		
		: BD439	$V_{CE} = 1V, I_{C} = 2A$	25			
		: BD441		15			
V _{CE} (sat)	* Collector-Emitter Saturation	on Voltage	I _C = 2A, I _B = 0.2A			0.8	V
V _{BE} (on)	* Base-Emitter ON Voltage		$V_{CE} = 5V, I_{C} = 10mA$		0.58		V
			$V_{CE} = 1V, I_{C} = 2A$			1.5	V
f _T	Current Gain Bandwidth Pr	oduct	$V_{CE} = 1V, I_{C} = 250 \text{mA}$	3			MHz

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